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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Applicant / Conf. No.	Unknown /
				Filing Date	November 12, 2003
				First Named Inventor	Kevin T. Look
				Art Unit	Unknown
				Examiner Name	Unknown
Sheet	2	of	2	Attorney Docket Number	X-1144 US

OTHER -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
		TOYOJI YAMAMOTO et al., "Bias Temperature Instability in Scaled p+ Polysilicon Gate p-MOSFET's," IEEE Transactions on Electron Devices, Vol. 46, No. 5, May 1999, IEEE, 3 Park Avenue, 17th Floor, New York, NY 10016-5997.	
		N. KIMIZUKA et al., "NBTI enhancement by nitrogen incorporation into ultrathin gate oxide for 0.10-um gate CMOS generation," 2000 Symposium on VLSI Technology Digest of Technical Papers, April 2000, pp. 92-93, IEEE, 3 Park Avenue, 17th Floor, New York, NY 10016-5997.	
		JEROME B. LASKY et al., "Comparison of Transformation to Low-Resistivity Phase and Agglomeration of TiSi ₂ and CoSi ₂ ," IEEE Transactions on Electron Devices, Vol. 38, No. 2, February 1991, pp. 262-269, IEEE, 3 Park Avenue, 17th Floor, New York, NY 10016-5997.	
		SE-AUG JANG et al., "Effects of Thermal Processes After Silicidation on the Performance of TiSi ₂ /Polysilicon Gate Device," IEEE Transactions on Electron Devices, Vol. 46, No. 12, December 1999, pp. 2353-2356, IEEE, 3 Park Avenue, 17th Floor, New York, NY 10016-5997.	
		MOHSEN ALAVI et al., A PROM Element Based on Salicide Agglomeration of Poly Fuses in a CMOS Logic Process, July 1997, pp. 855-858, IEEE, 3 Park Avenue, 17th Floor, New York, NY 10016-5997.	
		ALEXANDER KALNITZKY et al., "CoSi ₂ integrated fuses on poly silicon for low voltage 0.18um CMOS applications, September 1999, pp. 765-768 IEEE, 3 Park Avenue, 17th Floor, New York, NY 10016-5997.	

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